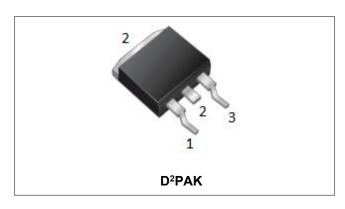


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RoHS 🗭

MBRB1560CT SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Circuit Diagram

Base common Cathode

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	60	V
Average Rectified Forward Current (Per Device)	lf (AV)	50% duty cycle @Tc=95°C, rectangular wave form	7.5(Per Leg) 15(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	150	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@ 15A, Pulse, T _J = 25 °C	0.85	0.90	V
(Per Leg) *	V _{F2}	@ 15A, Pulse, T _J = 125 °C	0.70	0.80	V
Reverse Current (Per Leg) *	I _{R1}	$@V_R = rated V_{R_j} T_J = 25 \ ^{\circ}C$	0.02	1.0	mA
	I _{R2}	$@V_R = rated V_{R_i} T_J = 125 \ ^{\circ}C$	9	50	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 \ ^{\circ}C, f_{SIG} = 1MHz$	180	300	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

* Pulse width < 300 µs, duty cycle < 2%

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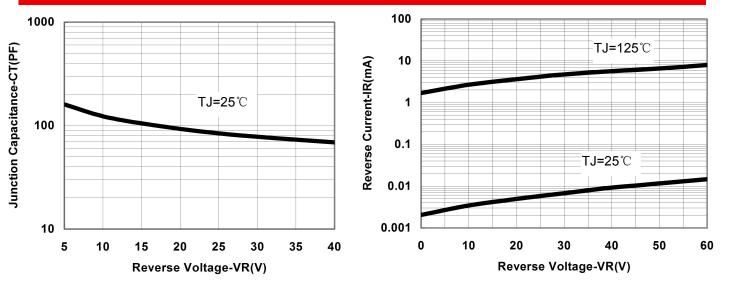
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Thermal-Mechanical Specifications:

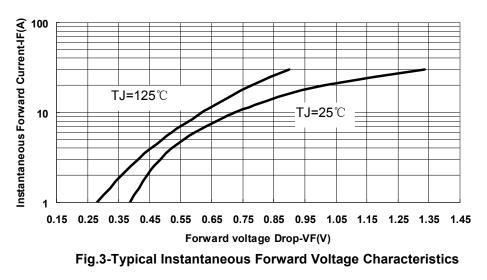
Characteristics	Symbol	Symbol Condition		Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R _θ JC	DC operation	2	°C/W
Typical Thermal Resistance Junction to Case(Per Leg)	R _{θJA}	DC operation	60	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D ² PAK			

Ratings and Characteristics Curves









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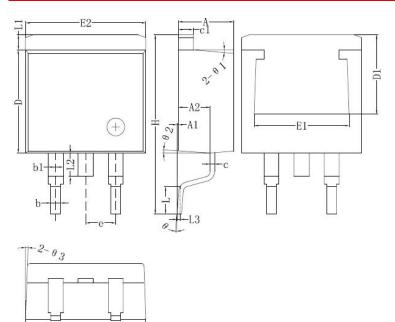


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Mechanical Dimensions D²PAK



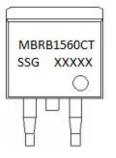
Symbol	Dimensions in millimeters			
,	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
e3		4 °		

Ordering Information

Device	Package	Shipping
MBRB1560CT	D ² PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

MBR

В

15

60 CT

SSG

YΥ

WW

L

= Device Type

= Package type = Forward Current (15A)

= Reverse Voltage(60V)

= Configuration

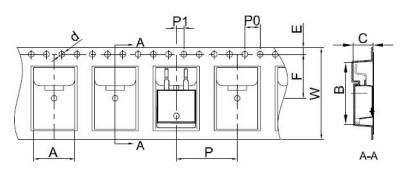
= SSG

= Year = Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



Millimeters		
Min.	Max.	
10.70	10.90	
16.03	16.23	
5.11	5.31	
1.45	1.65	
1.65	1.85	
11.40	11.60	
3.90	4.10	
15.90	16.10	
1.90	2.10	
23.90	24.30	
	Min. 10.70 16.03 5.11 1.45 1.65 11.40 3.90 15.90 1.90	

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